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Kinetic studies of few-layer graphene grown by flame deposition from the perspective of gas composition and temperature (Article) (Open Access)

Ismail, E.[a], Fauzi, F.B.[a], Mohamed, M.A.[b], Mohd Yasin, M.F.[c], Mohd Abid, M.A.A.[d], Yaacob, I.I.[a], Md Din, M.F.[e], Ani, M.H.[a]

[a]Department of Manufacturing and Materials, Kulliyyah of Engineering, International Islamic University Malaysia, P. O. Box 10, Kuala Lumpur, 50728, Malaysia
[b]Institute of Microengineering and Nanoelectronic, Universiti Kebangsaan Malaysia, Bangi, 43600, Malaysia
[c]High Speed Reacting Flow Laboratory (HiREF), Universiti Teknologi Malaysia, Johor Bahru, 81310, Malaysia

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Abstract

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Studies on depositions of chemical vapour deposition (CVD) diamond films have shown that flame combustion has the highest deposition rates without involving microwave plasma and direct current arc. Thus, here we report on our study of few-layer graphene grown by flame deposition. A horizontal CVD reactor was modified for the synthesis of flame deposition of few-layer graphene on a Cu substrate. It was found that graphene obtained has comparable quality to that obtained with other flame deposition setups reported in the literature as determined from Raman spectroscopy, sheet resistance, and transmission electron microscopy. Calculation of the chemical kinetics reveals a gas phase species that has a close correlation to the growth rate of graphene. This was further correlated with van't Hoff analysis of the reaction, which shows that the growth reaction has a single dominating mechanism for temperatures in the range of 400 °C to 1000 °C. Arrhenius analysis also was found to be in good agreement with this result. This study shows few-layer graphene growth proceeds through different pathways from a CVD grown graphene and also highlights flame deposition as a viable method for graphene growth. © 2019 The Royal Society of Chemistry.

SciVal Topic Prominence

Topic: Graphene | Chemical vapor deposition | Graphene synthesis

Prominence percentile: 99.753

Indexed keywords

Engineering controlled terms: Chemical vapor deposition, Combustion, Deposition rates, Diamond films, Flame resistance, Flame spraying, Gas dynamics, Growth kinetics, Growth rate, High resolution transmission electron microscopy

Engineering uncontrolled terms: Arrhenius analysis, Chemical vapour deposition, CVD-grown graphene, Few-layer graphene, Flame depositions, Gas compositions, Gas-phase species, Van't Hoff Analysis

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